

# 2K x 8 Automotive Dual-port Static RAM

### **Features**

- True dual-ported memory cells that allow simultaneous reads of the same memory location
- Automotive temperature operation: -40C to +115°C
- 2K x 8 organization
- · High-speed access: 55 ns
- Low operating power: Ł<sub>C</sub> = 120 mA (max.)
- · Fully asynchronous operation
- · Automatic power-down
- Master CG5982AF easily expands data bus width to 16 or more bits using slave
- BUSYoutput flag
- · INTflag for port-to-port communication

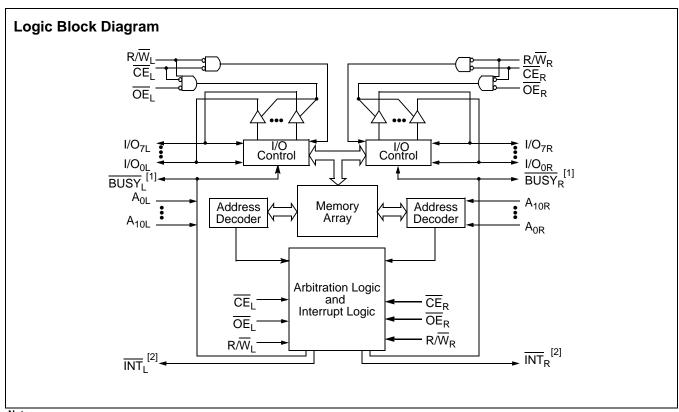
### **Functional Description**

The CG5982AF are high-speed CMOS 2K x 8 dual-port static RAMs. Two ports are provided to permit independent access to any location in memory. The CG5982AF can be utilized as either a standalone 8-bit dual-port static RAM or as a MASTER dual-port RAM in conjunction with the CG5982AF SLAVE dual-port device in systems requiring 16-bit or greater word widths. It is the solution to applications requiring shared or buffered data such as cache memory for DSP, bit-slice, or multiprocessor designs.

Each port has <u>independent</u> control pins; <u>chip enable</u> ( $\overline{CE}$ ), write enable (R/W), and output enable ( $\overline{OE}$ ). BUSY flags are provided on each port. In addition, an interrupt flag ( $\overline{INT}$ ) is provided on each port of the 52-pin PLCC version. BUSY signals that the port is trying to access the same location currently <u>being</u> accessed by the other port. On the PLCC version,  $\overline{INT}$  is an interrupt flag indicating that data has been placed in a unique location (7FF for the left port and 7FE for the right port).

An automatic power-down feature is controlled independently on each port by the chip enable (CE) pins.

The CG5982AF is available in a 52-pin PLCC package.



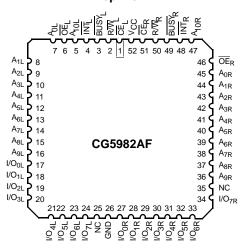
Notes:

- 1. CG5982AF (Master): BUSY is open-drain output and requires pull-up resistor.
- 2. Open drain outputs; pull-up resistor required.



### **Pin Configurations**

### **PLCC Top View**



### **Selection Guide**

	CG5982AF	Unit
Maximum Access Time	55	ns
Maximum Operating Current	120	mA
Maximum Standby Current	45	mA

### **Maximum Ratings**

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature ......-65°C to +150°C

Ambient Temperature with

Power Applied.......55°C to +125°C

Supply Voltage to Ground Potential

DC Voltage Applied to Outputs

in High-Z State ......-0.5V to +7.0V

DC Input Voltage	3.5V to +7.0V
Output Current into Outputs (LOW)	20 mA
Static Discharge Voltage(per MIL-STD-883, Method 3015)	> 2001V
Latch-up Current	> 200 mA

### **Operating Range**

Range	Ambient Temperature	V <sub>CC</sub>
Automotive <sup>[3]</sup>	–40°C to +115°C	5V ± 10%

### Electrical Characteristics Over the Operating Range<sup>[4]</sup>

			CG5982AF			
Parameter	Description	Test Conditions	Min.	Max.	Unit	
V <sub>OH</sub>	Output HIGH Voltage	$V_{CC} = Min., I_{OH} = -4.0 \text{ mA}$	2.4		V	
V <sub>OL</sub>	Output LOW Voltage	I <sub>OL</sub> = 4.0 mA		0.4	V	
		I <sub>OL</sub> = 16.0 mA <sup>[5]</sup>		0.5		
V <sub>IH</sub>	Input HIGH Voltage		2.2		V	
V <sub>IL</sub>	Input LOW Voltage			0.8	V	
I <sub>IX</sub>	Input Load Current	$GND \leq V_I \leq V_CC$	<b>-</b> 5	+5	μΑ	
l <sub>OZ</sub>	Output Leakage Current	$GND \le V_O \le V_{CC}$ , Output Disabled	-5	+5	μΑ	
I <sub>OS</sub>	Output Short–Circuit Current <sup>[6]</sup>	V <sub>CC</sub> = Max., V <sub>OUT</sub> = GND		-350	mA	

- 3.  $T_A$  is the "instant on" case temperature.
- 4. See the last page of this specification for Group A subgroup testing information.
  5. BUSY and INT pins only.
  6. Duration of the short circuit should not exceed 30 seconds.



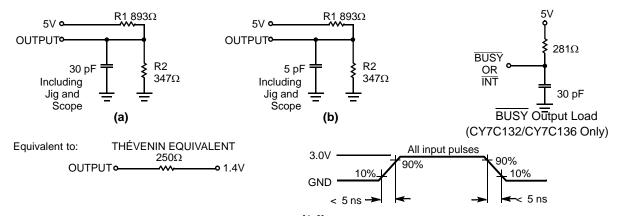
## **Electrical Characteristics** Over the Operating Range<sup>[4]</sup> (continued)

				CG59	982AF	
Parameter	Description	Test Conditions		Min.	Max.	Unit
Icc	V <sub>CC</sub> Operating Supply Current	CE = V <sub>IL</sub> , Outputs Open, f = f <sub>MAX</sub> [7]	Auto		120	mA
I <sub>SB1</sub>	Standby Current Both Ports, TTL Inputs	$\overline{CE}_L$ and $\overline{CE}_R \ge V_{IH}$ , $f = f_{MAX}^{[7]}$	Auto		45	mA
I <sub>SB2</sub>	Standby Current One Port, TTL Inputs	$\overline{CE}_L$ or $\overline{CE}_R \ge V_{IH}$ , Active Port Outputs Open, $f = f_{MAX}^{[7]}$	Auto		90	mA
I <sub>SB3</sub>	Standby Current Both Ports, CMOS Inputs	Both Ports $\overline{CE}_L$ and $\overline{CE}_R \ge V_{CC} - 0.2V$ , $V_{IN} \ge V_{CC} - 0.2V$ or $V_{IN} \le 0.2V$ , $f = 0$	Auto		15	mA
I <sub>SB4</sub>	Standby Current One Port, CMOS Inputs	One Port $\overline{\text{CE}}_{\text{L}}$ or $\overline{\text{CE}}_{\text{R}} \ge \text{V}_{\text{CC}}$ - 0.2V, $\text{V}_{\text{IN}} \ge \text{V}_{\text{CC}}$ - 0.2V or $\text{V}_{\text{IN}} \le 0.2$ V, Active Port Outputs Open, $\text{f} = \text{f}_{\text{MAX}}^{[7]}$	Auto		85	mA

## Capacitance<sup>[8]</sup>

Parameter	Description	Test Conditions	Max.	Unit
C <sub>IN</sub>	Input Capacitance	$T_A = 25^{\circ}C$ , $f = 1$ MHz,	15	pF
C <sub>OUT</sub>	Output Capacitance	$V_{CC} = 5.0V$	10	pF

### **AC Test Loads and Waveforms**



## Switching Characteristics Over the Operating Range<sup>[4, 9]</sup>

		CG59	CG5982AF	
Parameter	Description	Min.	Min. Max.	
Read Cycle		•	•	•
t <sub>RC</sub>	Read Cycle Time	55		ns
t <sub>AA</sub>	Address to Data Valid <sup>[10]</sup>		55	ns
t <sub>OHA</sub>	Data Hold from Address Change	0		ns
t <sub>ACE</sub>	CE LOW to Data Valid <sup>[10]</sup>		55	ns
t <sub>DOE</sub>	OE LOW to Data Valid <sup>[10]</sup>		25	ns
t <sub>LZOE</sub>	OE LOW to Low-Z <sup>[8, 11]</sup>	3		ns

### Notes:

- 7. At f = f<sub>MAX</sub>, address and data inputs are cycling at the maximum frequency of read cycle of 1/t<sub>rc</sub> and using AC Test Waveforms input levels of GND to 3V.
- 8. This parameter is guaranteed but not tested.
- 9. Test conditions assume signal transition times of 5 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V, output loading of the specified I<sub>OL</sub>/I<sub>OH</sub>, and 30-pF load capacitance.

  10. AC test conditions use V<sub>OH</sub> = 1.6V and V<sub>OL</sub> = 1.4V.

  11. At any given temperature and voltage condition for any given device, t<sub>HZCE</sub> is less than t<sub>LZCE</sub> and t<sub>HZOE</sub> is less than t<sub>LZCE</sub>.

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## **Switching Characteristics** Over the Operating Range<sup>[4, 9]</sup> (continued)

		CG5	982AF		
Parameter	Description	Min.	Max.	Unit	
t <sub>HZOE</sub>	OE HIGH to High-Z <sup>[8, 11, 12]</sup>		25	ns	
t <sub>HZCE</sub>	CE HIGH to High-Z <sup>[8, 11, 12]</sup>		25	ns	
t <sub>PU</sub>	CE LOW to Power-Up <sup>[8]</sup>	0		ns	
t <sub>PD</sub>	CE HIGH to Power-Down <sup>[8]</sup>		35	ns	
Write Cycle <sup>[13]</sup>					
t <sub>WC</sub>	Write Cycle Time	55		ns	
t <sub>SCE</sub>	CE LOW to Write End	40		ns	
$t_{AW}$	Address Set-up to Write End	40		ns	
t <sub>HA</sub>	Address Hold from Write End	2		ns	
t <sub>SA</sub>	Address Set-up to Write Start	0		ns	
t <sub>PWE</sub>	R/W Pulse Width	30		ns	
t <sub>SD</sub>	Data Set-up to Write End	20		ns	
t <sub>HD</sub>	Data Hold from Write End	0		ns	
t <sub>HZWE</sub>	R/W LOW to High-Z <sup>[8]</sup>		25	ns	
t <sub>LZWE</sub>	R/W HIGH to Low-Z [8]	0		ns	
Busy/Interrupt Timi	ng				
t <sub>BLA</sub>	BUSY LOW from Address Match		30	ns	
t <sub>BHA</sub>	BUSY HIGH from Address Mismatch <sup>[14]</sup>		30	ns	
t <sub>BLC</sub>	BUSY LOW from CE LOW		30	ns	
t <sub>BHC</sub>	BUSY HIGH from CE HIGH <sup>[14]</sup>		30	ns	
t <sub>PS</sub>	Port Set-up for Priority	5		ns	
t <sub>WB</sub>	R/W LOW after BUSY LOW	0		ns	
$t_{WH}$	R/W HIGH after BUSY HIGH	35		ns	
t <sub>BDD</sub>	BUSY HIGH to Valid Data		45	ns	
t <sub>DDD</sub>	Write Data Valid to Read Data Valid		Note 15	ns	
t <sub>WDD</sub>	Write Pulse to Data Delay		Note 15	ns	
Interrupt Timing <sup>[15]</sup>	•		•		
t <sub>WINS</sub>	R/W to INTERRUPT Set Time		45	ns	
t <sub>EINS</sub>	CE to INTERRUPT Set Time		45	ns	
t <sub>INS</sub>	Address to INTERRUPT Set Time	Address to INTERRUPT Set Time 45		ns	
t <sub>OINR</sub>	OE to INTERRUPT Reset Time <sup>[14]</sup>		45	ns	
t <sub>EINR</sub>			45	ns	
t <sub>INR</sub>	Address to INTERRUPT Reset Time <sup>[14]</sup>		45	ns	

Notes:

12. t<sub>LZCE</sub>, t<sub>LZWE</sub>, t<sub>HZOE</sub>, t<sub>HZCE</sub>, and t<sub>HZWE</sub> are tested with C<sub>L</sub> = 5 <u>p</u>F, as in (b) of <u>AC</u> Test Loads. Transition is measured ± 500 mV from steady-state voltage.

13. The internal write time of the memory is defined by the overlap of <u>CE</u> LOW and RW LOW. Both signals must be LOW to initiate a write and either signal can terminate a write by going HIGH. The data input setup and hold timing should be referenced to the rising edge of the signal that terminates the write.

14. These parameters are measured from the input signal changing, until the output pin goes to a high-impedance state.

15. <u>A write</u> operation on Port A, where Port A has priority, leaves the data on Port B's outputs undisturbed until one access time after one of the following: BUSY on Port B goes HIGH.

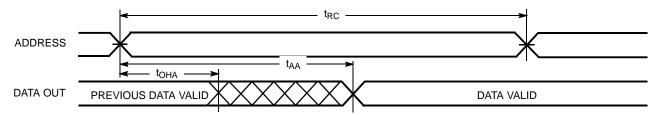
Port B's address toggled.

CE for Port B is toggled during valid read.

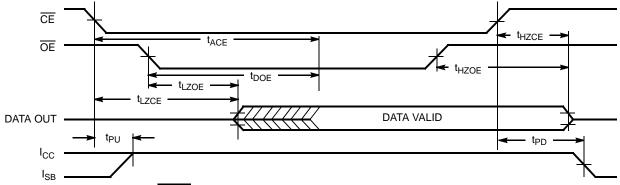


### **Switching Waveforms**

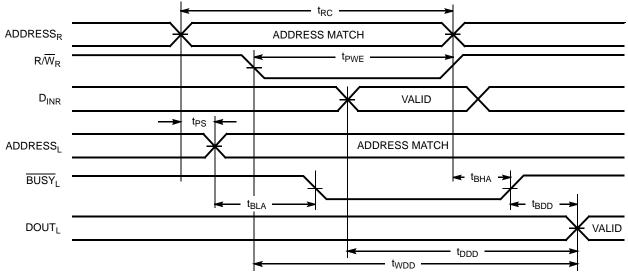
## Read Cycle No. 1 (Either Port-Address Access)<sup>[16, 17]</sup>



## Read Cycle No. 2 (Either Port- $\overline{CE}/\overline{OE}$ )[16, 18]



### Read Cycle No. 3 (Read with BUSY Master)



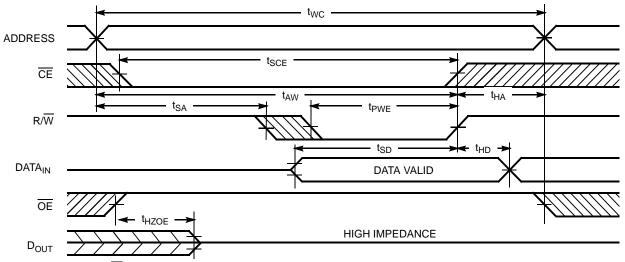
- 16. R/W is HIGH for read cycle.
- 17. Device is continuously selected,  $\overline{\text{CE}} = \text{V}_{\text{IL}}$  and  $\overline{\text{OE}} = \text{V}_{\text{IL}}$ .

  18. Address valid prior to or coincident with  $\overline{\text{CE}}$  transition LOW.

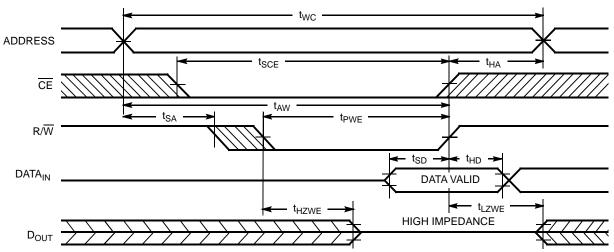


## Switching Waveforms (continued)

Write Cycle No.1 (OE Three-States Data I/Os—Either Port)[13, 19]



Write Cycle No. 2 (R/ $\overline{\mathbf{W}}$  Three-States Data I/Os—Either Port) $^{[13, 20]}$ 



Notes:

19. If  $\overline{OE}$  is LOW during a R $\overline{W}$  controlled write cycle, the write pulse width must be the larger of  $t_{PWE}$  or  $t_{HZWE} + t_{SD}$  to allow the data I/O pins to enter high impedance and for data to be placed on the bus for the required  $t_{SD}$ .

20. If the  $\overline{CE}$  LOW transition occurs simultaneously with or after the R $\overline{W}$  LOW transition, the outputs remain in a high-impedance state.



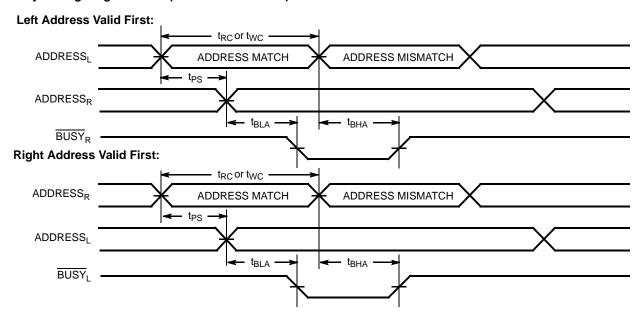
## **Switching Waveforms** (continued)

## **Busy Timing Diagram No. 1 (CE Arbitration)**

## $\overline{\text{CE}}_{\text{L}}$ Valid First: ADDRESS<sub>L,R</sub> ADDRESS MATCH CE<sub>L</sub> Œ<sub>R</sub> $t_{BLC}$ ← t<sub>BHC</sub> → BUSYR $\overline{\text{CE}}_{\text{R}}$ Valid First: $\mathsf{ADDRESS}_{\mathsf{L},\mathsf{R}}^{\mathsf{T}}$ ADDRESS MATCH CE<sub>R</sub>-< t<sub>PS</sub> → CE, $t_{BLC}$ − t<sub>BHC</sub> →

### **Busy Timing Diagram No. 2 (Address Arbitration)**

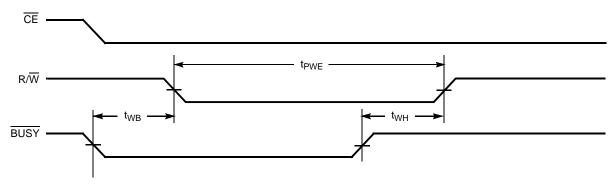
BUSYL





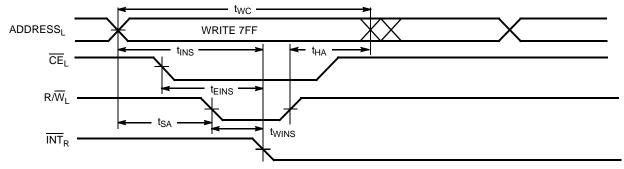
## Switching Waveforms (continued)

## Busy Timing Diagram No. 3 (Write with BUSY, Slave)

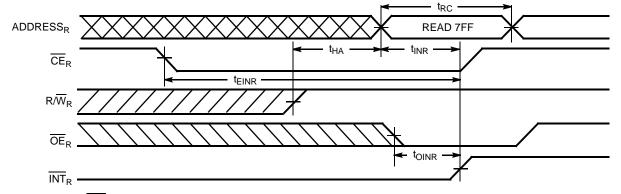


# Interrupt Timing Diagrams<sup>[16]</sup>

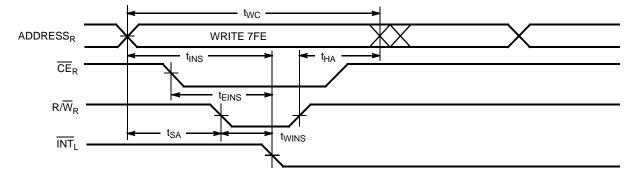
## Left Side Sets INT<sub>R</sub>:



## Right Side Clears INT<sub>R</sub>:



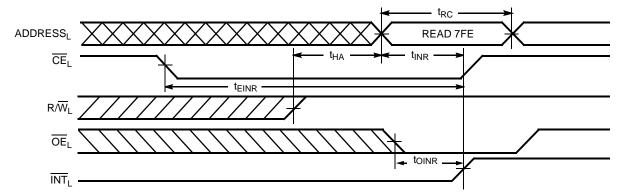
### Right Side Sets INT<sub>L</sub>:





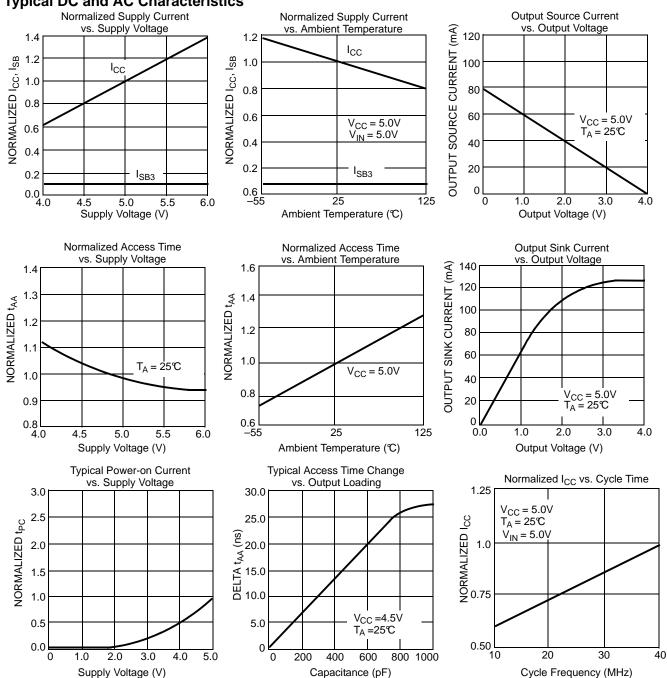
# Interrupt Timing Diagrams<sup>[16]</sup> (continued)

Left Side Clears  $\overline{\text{INT}}_{\text{L}}$ :









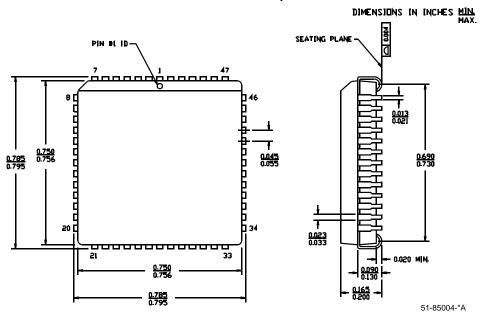
## **Ordering Information**

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
55	CG5982AF	J69	52-lead Plastic Leaded Chip Carrier	Automotive



## **Package Diagrams**

### 52-lead Plastic Leaded Chip Carrier J69



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# **Document History Page**

	Document Title: CG5982AF 2K x 8 Automotive Dual-port Static RAM Document Number: 38-06067					
REV.	ECN	Issue Date	Orig. of Change	Description of Change		
**	119657	10/10/02	NIM	Customized data sheet to meet special requirements for CG5982AF; automotive temperature –40°C to +115°C; base part in CY7C136		
*A	121488	12/09/02	OOR	Fixed Typo- changed 5 mA to 5 μA (p.2)		
*B	393195	SEE ECN	KGH	Included the automotive temperature operation range to the Features section Removed the micron CMOS size and the 52-pin PLCC references from the Features section Added Automotive to the title description		
*C	421244	See ECN	ODC	Add to external web.		